

We are so pleased to announce the recipients of AM-FPD '18 Award.

They will be presented the award in the Opening Session of AM-FPD '19 on July 2, 2019.

AM-FPD '18 Best Paper Award

3-2 **High-Performance Solution-Processed Thin-Film Transistors Using Fluorine-Doped Aqueous Metal Oxides**

Masashi Miyakawa, Mitsuru Nakata, Hiroshi Tsuji, Yoshihide Fujisaki, *NHK Sci. & Technol. Res. Labs., Japan*

AM-FPD '18 Poster Paper Award

P-16 **Flexible Thin-Film Transistors with Vertical In-Ga-Zn-O Channel Using Atomic-Layer Deposition on Poly(Ethylene Naphthalate) Substrate**

Hyeong Rae Kim¹, Ji-Hee Yang¹, Gi-Heon Kim², Sung-Min Yoon¹, ¹*Kyung Hee Univ., Korea*, ²*Electronics & Telecommunication Res. Inst., Korea*

AM-FPD '18 Student Award

So-Yeong Na, *Kyung Hee Univ., Korea*

5-3 **Characterizations of Charge-Trap Memory Thin-Film Transistors Using HfO₂/ZnO Stack-Structured Charge-Trap Layer Controlled by Atomic Layer Deposition**

AMFPD '18-ECS Japan Section Young Researcher Award

Taehwan Jun, *Tokyo Inst. of Technol., Japan*,

L-1 **Solution-Processable P-type Transparent Amorphous Semiconductor for Flexible Electronics**